Nano Structured Composite Materials for Thermoelectric Applications

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## Thermoelectricity

연구분야

온도차에 의해 기전력이 발생하는 현상(Seebeck 효과) 또는 전류에 의해 열이 흡수,발생이 생기는 현상 (Peltier효과)

#### 응용분야



www.spaceref.com/news/viewpr.html?pid=18796

## **Configuration of Thermoelectric Module**







Laser Cooling Modules

**Thermoelectric Figure of Merit** 

## $Z = \alpha^2 \sigma / \kappa$

Seebeck coeff. (α) : morphology, doping state
Electrical conductivity(σ) : carrier concentration

• Thermal conductivity (κ) : phonon scattering

## **Optimum Transport Coefficients**



Figure of Merit : ZT

$$ZT = \frac{S^2 \sigma T}{k} \qquad \kappa = \kappa_e + \kappa_{ph}$$

- High Seebeck coefficient
- High electrical conductivity
- Low thermal conductivity

Difficulties in increasing ZT in bulk materials :

 $S \uparrow \leftrightarrow \sigma \downarrow$ 

$$\sigma \uparrow \leftrightarrow S \downarrow and k \uparrow$$

## **Selection Criteria for Candidate Materials**

$$Z_{\rm max} \propto \gamma \frac{T^{3/2} \tau \sqrt{\frac{m_x m_y}{m_z}}}{k_{latt}} e^{(r+1/2)}$$

- m = effective mass
- $\tau$  = scattering time
- r = scattering parameter
- $k_{\text{latt}} = \text{lattice thermal}$
- conductivity
- T = temperature
- $\gamma$  = band degeneracy

## **Guiding Principles:**

- Narrow band-gap semiconductors : Single carrier systems
- $\Box$  Heavy elements : High  $\mu$ , low  $\kappa$
- $\Box$  Large unit cell, complex structure : low  $\kappa$
- Highly anisotropic or highly symmetric
- $\Box$  Complex compositions : low  $\kappa$ , complex electronic structure
- $\Box$  Mass Fluctuation : low  $\kappa$
- □ High density of states near the Fermi level : high Seebeck

coefficient

## **New direction : Nano-based Thermoelectrics**

 Minimizing the thermal conductivity : Thermal conductivity can be significantly reduced by the scattering of unwanted heat flow at the interfaces



 Maximizing Seebeck coefficient: Electronic properties may be dramatically modified due to the electron confinement in nanostructures which exhibit lowdimensional behaviors.







## New Approach

#### Nanoparticles Embedded in Bulk Thermoelectric Materials



Matrixes	Nanoparticles	Nanorods	
PbTe Bi <sub>2</sub> Te <sub>3</sub> In <sub>2</sub> Te <sub>3</sub>	$\begin{array}{c} Bi_2Te_3\\Bi_2Se_3\\Sb_2Te_3\\Bi_xSb_{2-x}Te_3\\Bi\end{array}$	Bi <sub>2</sub> Te <sub>3</sub> CdSe Te	

## **Synthesis of Various Nanoparticles**



## **Sample preparation and measurements**





Nanocomposite ingot



sawing





Polishing (400 - 2000 - micro)







Thermal conductivity measurement





Nanocomposite sample

## Sample Preparation

#### Nano-structured Bulk Thermoelectirc Material

#### PbTe ingot with Bi<sub>2</sub>Te<sub>3</sub> nanoparticle



PbTe



#### Bi<sub>2</sub>Te<sub>3</sub> nanoparticles(~150nm)







PbTe with Bi<sub>2</sub>Te<sub>3</sub> ingot

## **Nano-Bulk Composite Thermoelectric Material**

#### PbTe ingot with Bi<sub>2</sub>Se<sub>3</sub> nanoparticle







PbTe

#### Bi<sub>2</sub>Se<sub>3</sub> nanoparticles(~80nm)





# **Nano-Bulk Composite Thermoelectric Material**

 $\rightarrow$ 

In<sub>2</sub>Te<sub>3</sub> ingot with Bi<sub>2</sub>Te<sub>3</sub> nanoparticle



In<sub>2</sub>Te<sub>3</sub> Matrix



(~150nm)







Power Factor increase with decreasing nanoparticle content



1. Remove 2. Electrochemically deposition

1. Remove 2. Electrochemically deposition barrier oxide layer Bi nanowire material

↓ 3. Electrochemically deposition
 Te nanowire material

↓ 4. Remove AAO template







•Scheme 1. Schamatic of the process employed to produce (a) superlattice structure (b) one element or binary nanowire arrays by pulsed-potential deposition into porous anodic alumina template

## SEM image Bi and Te NWs





열전재료용 나노입자, 나노선 제조		Bulk에 나노입자, 나노선 삽입	
Hydrothermal법을 이용한 Bi <sub>2</sub> Te <sub>3</sub> 의 morphologies	-	PbTe ingot with Bi <sub>2</sub> Te <sub>3</sub>	
Colloidal법을 이용한 Bi <sub>2</sub> Te <sub>3</sub> 나노입자			14. AL
Bi <sub>2</sub> Se <sub>3</sub> 나노입자		PbTe ingot with Bi <sub>2</sub> Se <sub>3</sub>	
Sb <sub>2</sub> Te <sub>3</sub> 나노입자			
Bi <sub>x</sub> Sb <sub>2-x</sub> Te <sub>3</sub> 나노입자		InTe ingot with Bi <sub>s</sub> Se <sub>s</sub>	
Bi 나노입자			
CdSe 나노선		InTe ingot with Bi Te	
전기화학법을 이용한 Bi, Te 나노선	and the second		

## Conclusions

## Nanostructured bulk CompositeTE materials

- New approaches are promising in raising ZT
- Strong thermal conductivity reduction can be achieved through nanostructuring
- Doping studies and processing conditions are important in ZT optimization

### Nanoparticles

- Nano particles of various TE materials are obtained

#### Nanocomposites

- New approaches was provide to control the size and concentration of the nanocomponent in bulk TE materials

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